Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

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Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

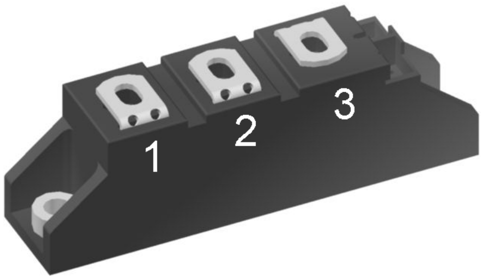
Standard Rectifier Module

V_{RRM} = 2x 1800 V
I_{FAV} = 120 A
V_F = 1.13 V

Phase leg

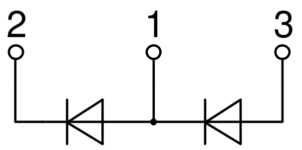
Part number

MDD95-18N1B



Backside: isolated

E72873



Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

Applications:

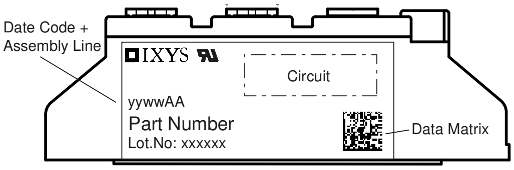
- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: TO-240AA

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Height: 30 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

Rectifier				Ratings			
Symbol	**Definition**	**Conditions**		**min.**	**typ.**	**max.**	**Unit**
V_{RSM}	*max. non-repetitive reverse blocking voltage*		T_{VJ} = 25°C			1900	V
V_{RRM}	*max. repetitive reverse blocking voltage*		T_{VJ} = 25°C			1800	V
I_R	*reverse current*	V_R = 1800 V	T_{VJ} = 25°C			200	µA
		V_R = 1800 V	T_{VJ} = 150°C			15	mA
V_F	*forward voltage drop*	I_F = 150 A	T_{VJ} = 25°C			1.20	V
		I_F = 300 A				1.43	V
		I_F = 150 A	T_{VJ} = 125°C			1.13	V
		I_F = 300 A				1.46	V
I_{FAV}	*average forward current*	T_C = 100°C	T_{VJ} = 150°C			120	A
$I_{F(RMS)}$	*RMS forward current*	180° sine				180	A
V_{F0}	*threshold voltage*	*for power loss calculation only*	T_{VJ} = 150°C			0.75	V
r_F	*slope resistance*					1.95	mΩ
R_{thJC}	*thermal resistance junction to case*					0.26	K/W
R_{thCH}	*thermal resistance case to heatsink*				0.20		K/W
P_{tot}	*total power dissipation*		T_C = 25°C			481	W
I_{FSM}	*max. forward surge current*	t = 10 ms; (50 Hz), sine	T_{VJ} = 45°C			2.80	kA
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			3.03	kA
		t = 10 ms; (50 Hz), sine	T_{VJ} = 150°C			2.38	kA
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			2.57	kA
I^2t	*value for fusing*	t = 10 ms; (50 Hz), sine	T_{VJ} = 45°C			39.2	kA²s
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			38.1	kA²s
		t = 10 ms; (50 Hz), sine	T_{VJ} = 150°C			28.3	kA²s
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			27.5	kA²s
C_J	*junction capacitance*	V_R = 400 V; f = 1 MHz	T_{VJ} = 25°C		116		pF

Package TO-240AA				Ratings			
Symbol	**Definition**	**Conditions**		**min.**	**typ.**	**max.**	**Unit**
I_{RMS}	*RMS current*	per terminal				200	A
T_{VJ}	*virtual junction temperature*			-40		150	°C
T_{op}	*operation temperature*			-40		125	°C
T_{stg}	*storage temperature*			-40		125	°C
Weight					76		g
M_D	*mounting torque*			2.5		4	Nm
M_T	*terminal torque*			2.5		4	Nm
$d_{Spp/App}$	*creepage distance on surface | striking distance through air*	*terminal to terminal*	13.0	9.7			mm
$d_{Spb/Apb}$		*terminal to backside*	16.0	16.0			mm
V_{ISOL}	*isolation voltage*	t = 1 second; 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA		3600			V
		t = 1 minute		3000			V

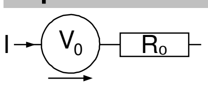


Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MDD95-18N1B	MDD95-18N1B	Box	36	454427

Similar Part	Package	Voltage class
MDD95-08N1B	TO-240AA	800
MDD95-12N1B	TO-240AA	1200
MDD95-14N1B	TO-240AA	1400
MDD95-16N1B	TO-240AA	1600

Equivalent Circuits for Simulation

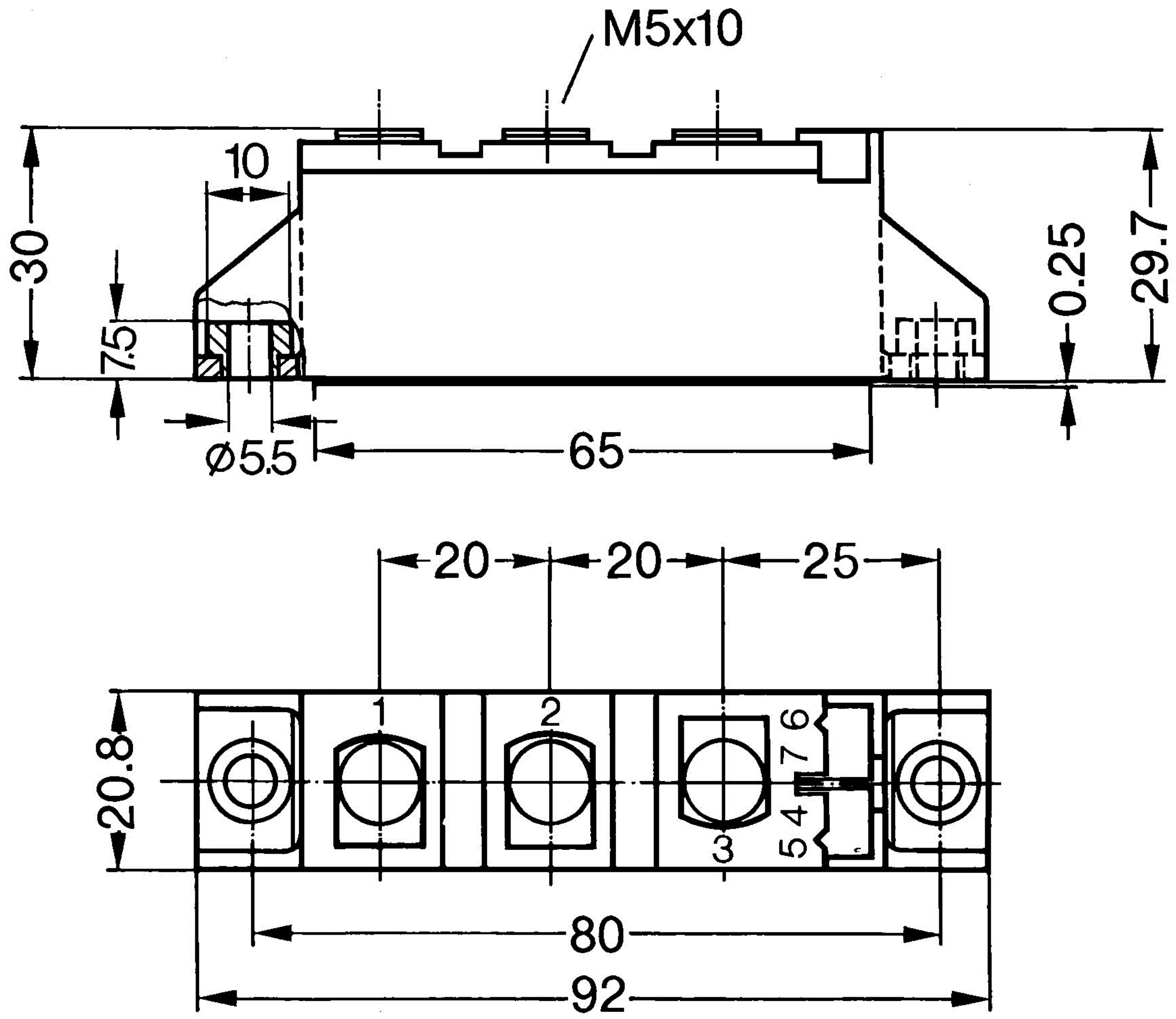
** on die level* $T_{VJ} = 150\,°C$

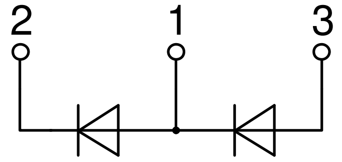


		Rectifier	
$V_{0\,max}$	*threshold voltage*	0.75	V
$R_{0\,max}$	*slope resistance **	0.76	mΩ

IXYS reserves the right to change limits, conditions and dimensions. Data according to IEC 60747and per semiconductor unless otherwise specified 20161222b

Outlines TO-240AA





Rectifier

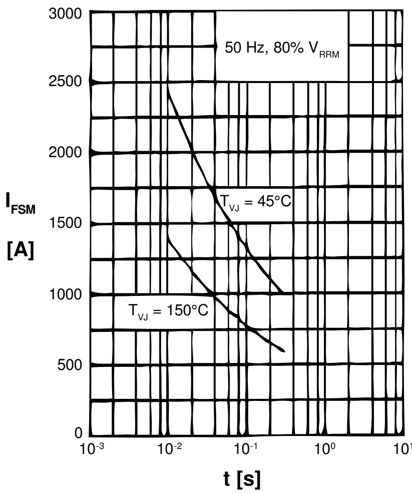


Fig. 1 Surge overload current
I_{TSM}, I_{FSM}: Crest value, t: duration

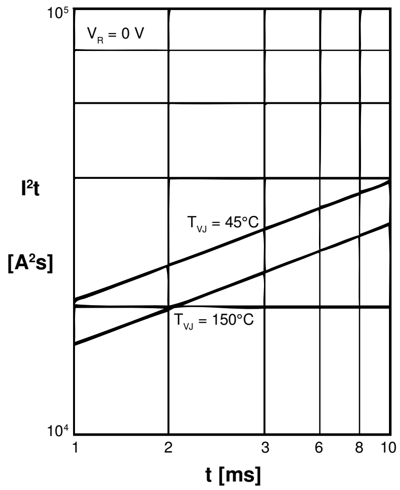


Fig. 2 I^2t versus time (1-10 ms)

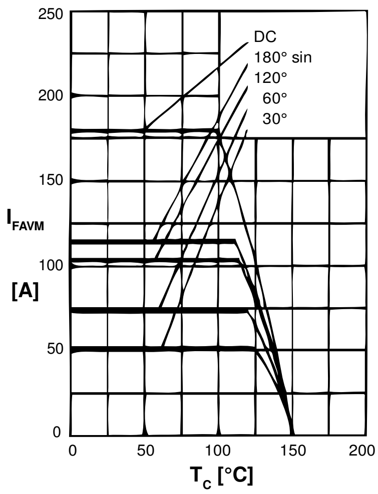


Fig. 3 Maximum forward current at case temperature

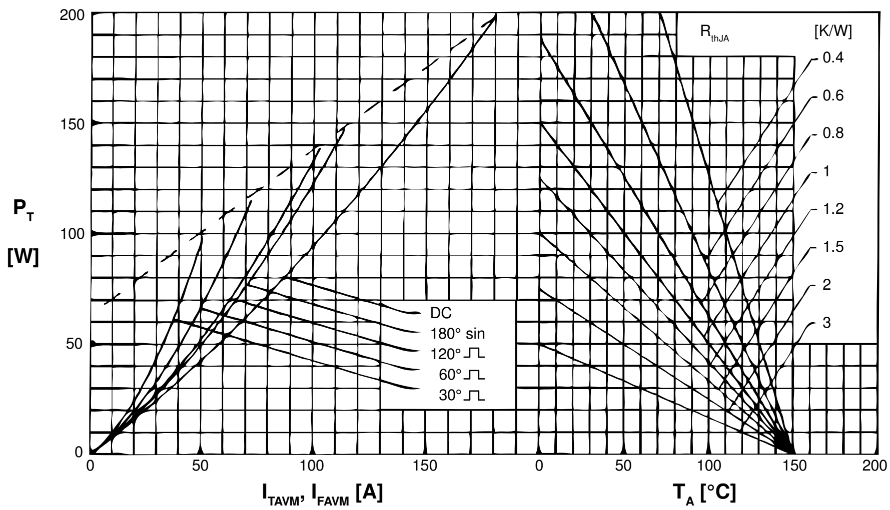


Fig. 4 Power dissipation vs. onstate current and ambient temperature (per diode)

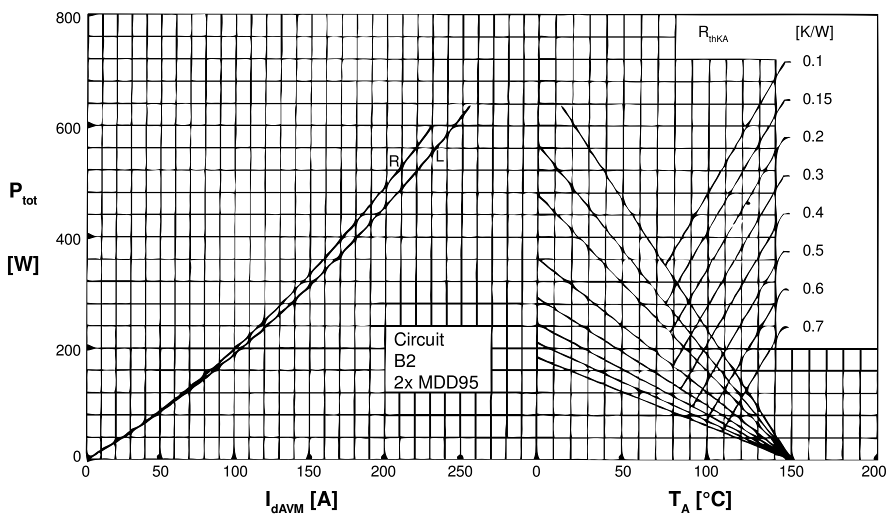


Fig. 6 Single phase rectifier bridge: Power dissipation versus direct output current and ambient temperature; R = resistive load, L = inductive load

Rectifier

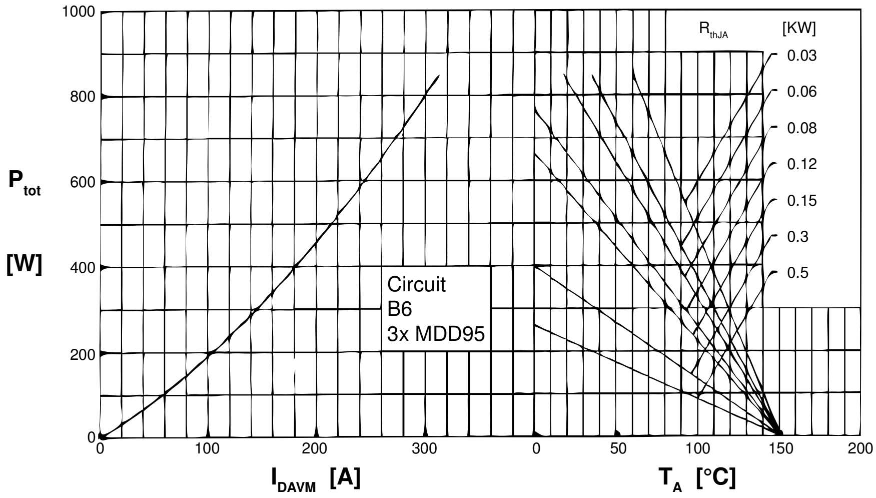


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

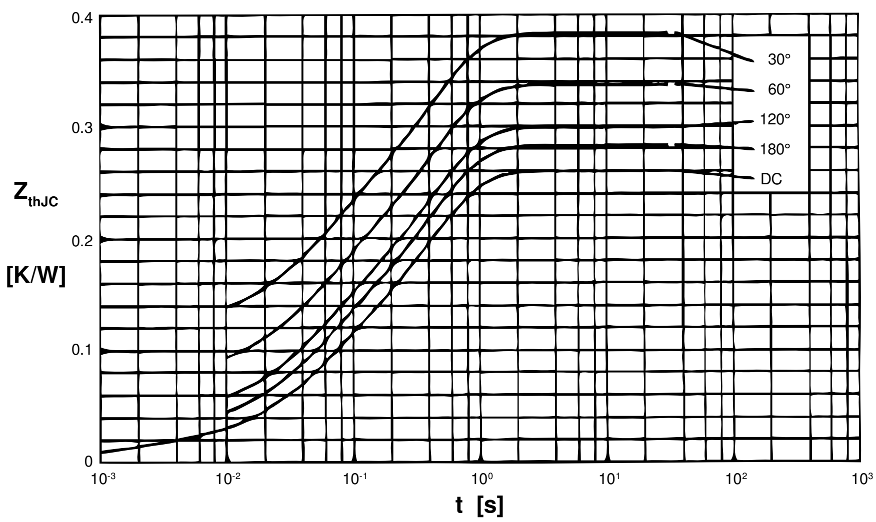


Fig. 7 Transient thermal impedance junction to case (per diode)

R_{thJC} for various conduction angles d:

d	R_{thJC} [K/W]
DC	0.26
180°	0.28
120°	0.30
60°	0.34
30°	0.38

Constants for Z_{thJC} calculation:

i	R_{thi} [K/W]	t_i [s]
1	0.013	0.0012
2	0.072	0.0470
3	0.175	0.3940

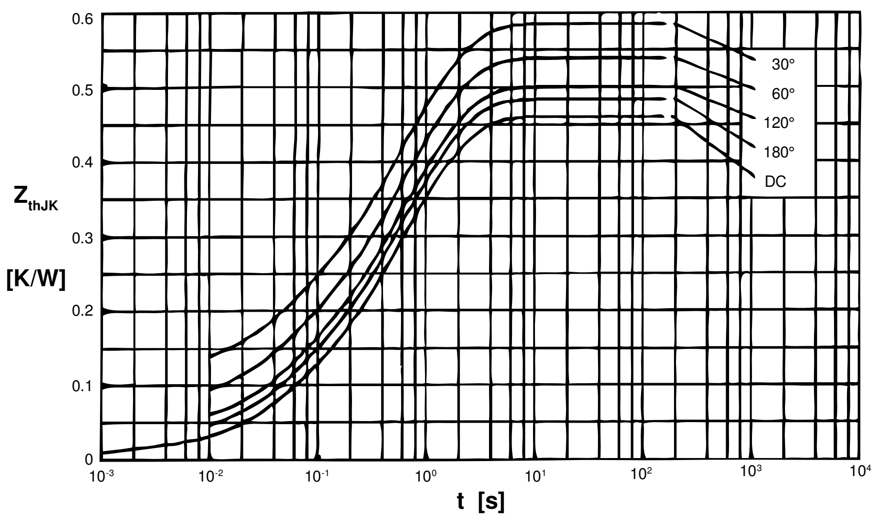


Fig. 8 Transient thermal impedance junction to heatsink (per thyristor)

R_{thJK} for various conduction angles d:

d	R_{thJK} [K/W]
DC	0.46
180°	0.48
120°	0.50
60°	0.54
30°	0.58

Constants for Z_{thJK} calculation:

i	R_{thi} [K/W]	t_i [s]
1	0.013	0.0012
2	0.072	0.0470
3	0.175	0.3940
4	0.200	1.3200